



JCS20N65H

主要参数 MAIN CHARACTERISTICS

I_D	20A
V_{DSS}	650 V
$R_{Dson-max}$ (@ $V_{gs}=10V$)	0.5 Ω
Q_g-typ	45nC

用途

- 高频开关电源
- 电子镇流器
- LED 电源

APPLICATIONS

- High frequency switching mode power supply
- Electronic ballast
- LED power supply

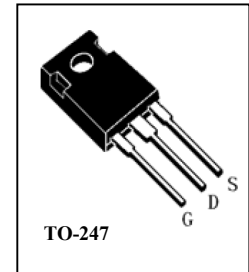
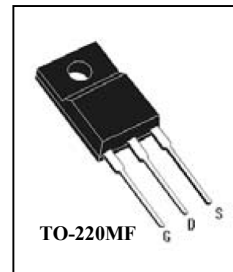
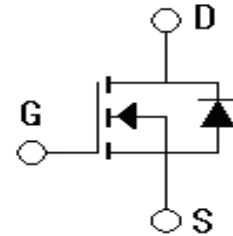
产品特性

- 低栅极电荷
- 低 C_{rss} (典型值 11pF)
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品

FEATURES

- Low gate charge
- Low C_{rss} (typical 11pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

封装 Package



订货信息 ORDER MESSAGE

订货型号 Order codes				印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen-Free-Tube	有卤-编带 Halogen-Reel	无卤-编带 Halogen-Free-Reel		
JCS20N65FH-F-B	JCS20N65FH-F-BR	N/A	N/A	JCS20N65FH	TO-220MF
JCS20N65WH-GE-B	JCS20N65WH-GE-BR	N/A	N/A	JCS20N65WH	TO-247





绝对最大额定值 ABSOLUTE RATINGS (Tc=25°C)

项 目 Parameter	符 号 Symbol	数 值 Value		单 位 Unit
		JCS20N65WH	JCS20N65FH	
最高漏极—源极直流电压 Drain-Source Voltage	V_{DSS}	650		V
连续漏极电流 Drain Current -continuous	I_D T=25°C	20		A
	T=100°C	12.5		A
最大脉冲漏极电流 (注 1) Drain Current – pulse (note 1)	I_{DM}	80		A
最高栅源电压 Gate-Source Voltage	V_{GSS}	±30		V
单脉冲雪崩能量 (注 2) Single Pulsed Avalanche Energy (note 2)	E_{AS}	108		mJ
雪崩电流 (注 1) Avalanche Current (note 1)	I_{AR}	20		A
重复雪崩能量 (注 1) Repetitive Avalanche Energy (note 1)	E_{AR}	20.7		mJ
二极管反向恢复最大电压变化速率 (注 3) Peak Diode Recovery dv/dt (note 3)	dv/dt	50		V/ns
耗散功率 Power Dissipation	P_D T _C =25°C	500	62.2	W
	-Derate above 25°C	4.0	0.5	W/°C
最高结温及存储温度 Operating and Storage Temperature Range	T _J , T _{STG}	-55~+150		°C
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T _L	300		°C

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature





项 目 Parameter	符 号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单位 Units
关态特性 Off –Characteristics						
漏—源击穿电压 Drain-Source Voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0V$	650	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS}/\Delta T_J$	$I_D=250\mu A$, referenced to $25^\circ C$	-	0.5	-	V/ $^\circ C$
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=650V, V_{GS}=0V,$ $T_C=25^\circ C$	-	-	10	μA
		$V_{DS}=520V, T_C=125^\circ C$	-	-	100	μA
正向栅极体漏电流 Gate-body leakage current, forward	I_{GSSF}	$V_{DS}=0V, V_{GS}=30V$	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I_{GSSR}	$V_{DS}=0V, V_{GS}=-30V$	-	-	-100	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	3.0	-	5.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS} = 10V, I_D=10A$	-	0.44	0.5	Ω
动态特性 Dynamic Characteristics						
输入电容 Input capacitance	C_{iss}	$V_{DS}=25V,$ $V_{GS}=0V,$ $f=1.0MHz$	-	2550	4000	pF
输出电容 Output capacitance	C_{oss}		-	250		pF
反向传输电容 Reverse transfer capacitance	C_{rss}		-	11		pF





电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics						
延迟时间 Turn-On delay time	$t_d(\text{on})$	$V_{DD}=300V, I_D=20A, R_G=25\Omega$ (note 4, 5)	-	56	128	ns
上升时间 Turn-On rise time	t_r		-	140	270	ns
延迟时间 Turn-Off delay time	$t_d(\text{off})$		-	80	350	ns
下降时间 Turn-Off Fall time	t_f		-	50	120	ns
栅极电荷总量 Total Gate Charge	Q_g	$V_{DS}=520V,$ $I_D=20A$ $V_{GS}=10V$ (note 4, 5)	-	45	80	nC
栅-源电荷 Gate-Source charge	Q_{gs}		-	15.0	-	nC
栅-漏电荷 Gate-Drain charge	Q_{gd}		-	17	-	nC
漏-源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings						
正向最大连续电流 Maximum Continuous Drain-Source Diode Forward Current		I_S	-	-	20	A
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current		I_{SM}	-	-	80	A
正向压降 Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V,$ $I_S=20A$	-	-	1.45	V
反向恢复时间 Reverse recovery time	t_{rr}	$V_{GS}=0V, I_S=20A$ $di/dt=100A/\mu s$ (note 4)	-	660	-	ns
反向恢复电荷 Reverse recovery charge	Q_{rr}		-	.9.3	-	μC

热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	最大 Max		单 位 Unit
		JCS20N65WH	JCS20N65FH	
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	0.25	2.01	$^{\circ}C/W$
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	29.8	39.7	$^{\circ}C/W$

注释:

- 1: 脉冲宽度由最高结温限制
- 2: $L=0.5mH, I_{AS}=20A, V_{DD}=50V, R_G=25\Omega$, 起始结温 $T_J=25^{\circ}C$
- 3: $I_{SD} \leq 9.5A, di/dt \leq 300A/\mu s, V_{DD} \leq BV_{DSS}$, 起始结温 $T_J=25^{\circ}C$
- 4: 脉冲测试: 脉冲宽度 $\leq 300\mu s$, 占空比 $\leq 2\%$
- 5: 基本与工作温度无关

Notes:

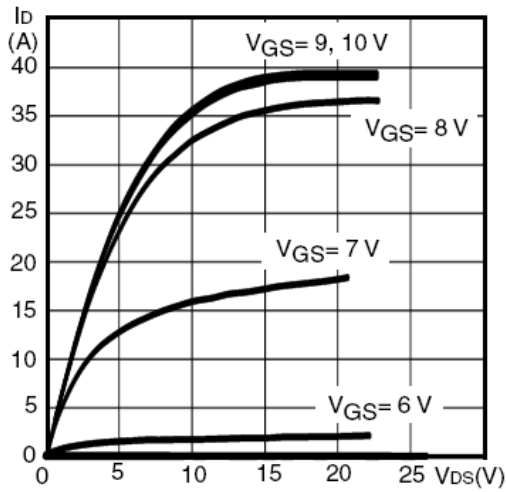
- 1: Pulse width limited by maximum junction temperature
- 2: $L=0.5mH, I_{AS}=20A, V_{DD}=50V, R_G=25\Omega$, Starting $T_J=25^{\circ}C$
- 3: $I_{SD} \leq 9.5A, di/dt \leq 300A/\mu s, V_{DD} \leq BV_{DSS}$, Starting $T_J=25^{\circ}C$
- 4: Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$
- 5: Essentially independent of operating temperature



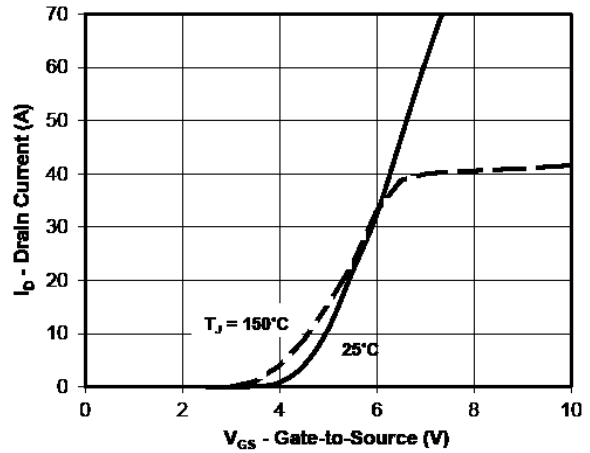


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

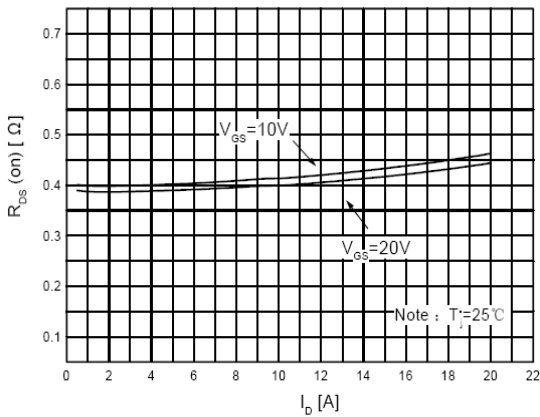
On-Region Characteristics



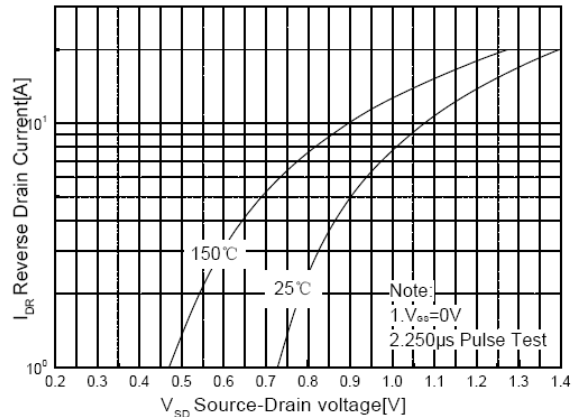
Transfer Characteristics



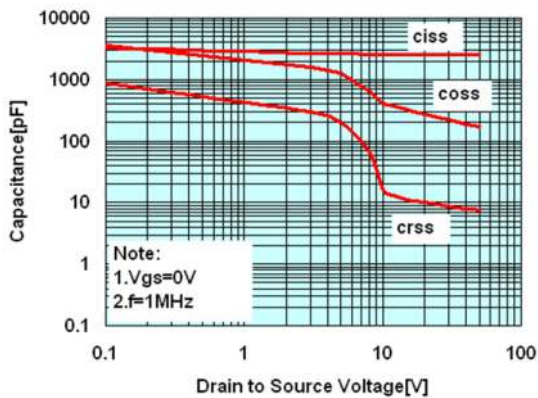
On-Resistance Variation vs. Drain Current and Gate Voltage



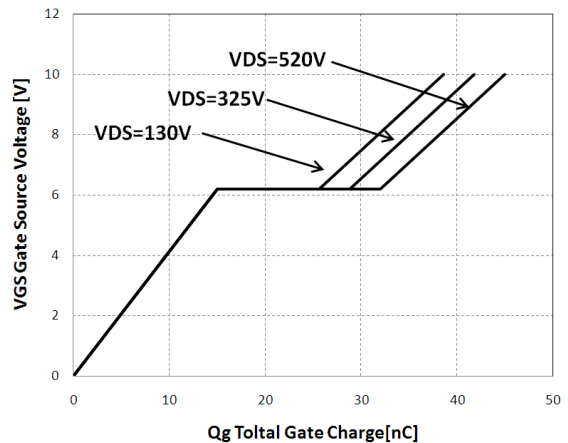
Body Diode Forward Voltage Variation vs. Source Current and Temperature



Capacitance Characteristics



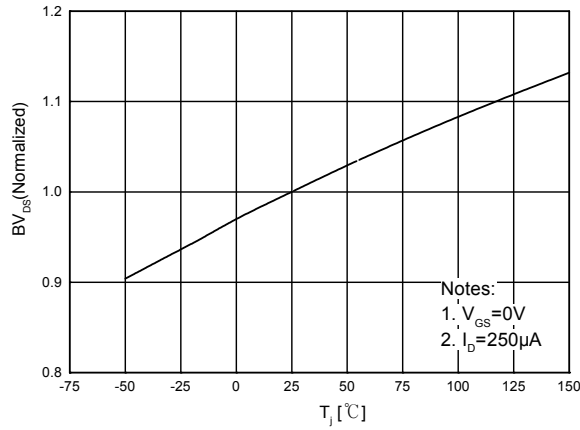
Gate Charge Characteristics



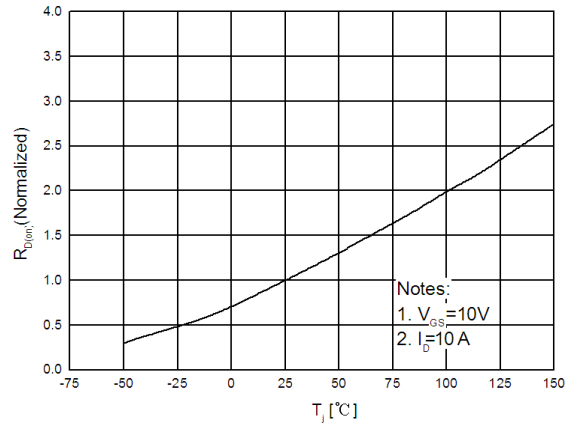


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

Breakdown Voltage Variation vs. Temperature



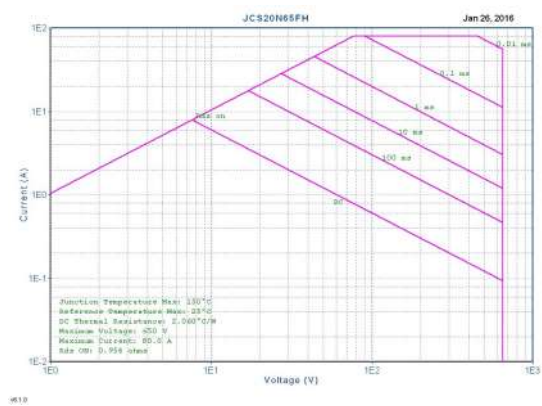
On-Resistance Variation vs. Temperature



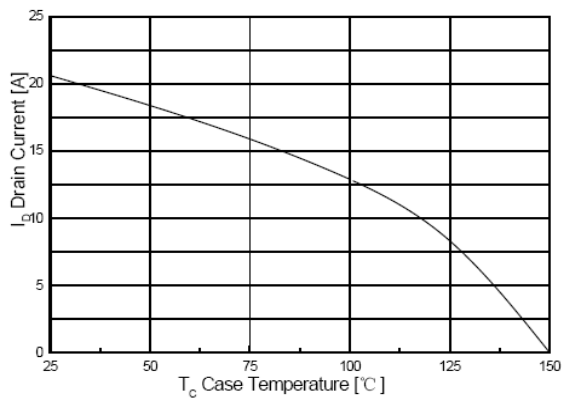
Maximum Safe Operating Area For JCS20N65WH



Maximum Safe Operating Area For JCS20N65FH

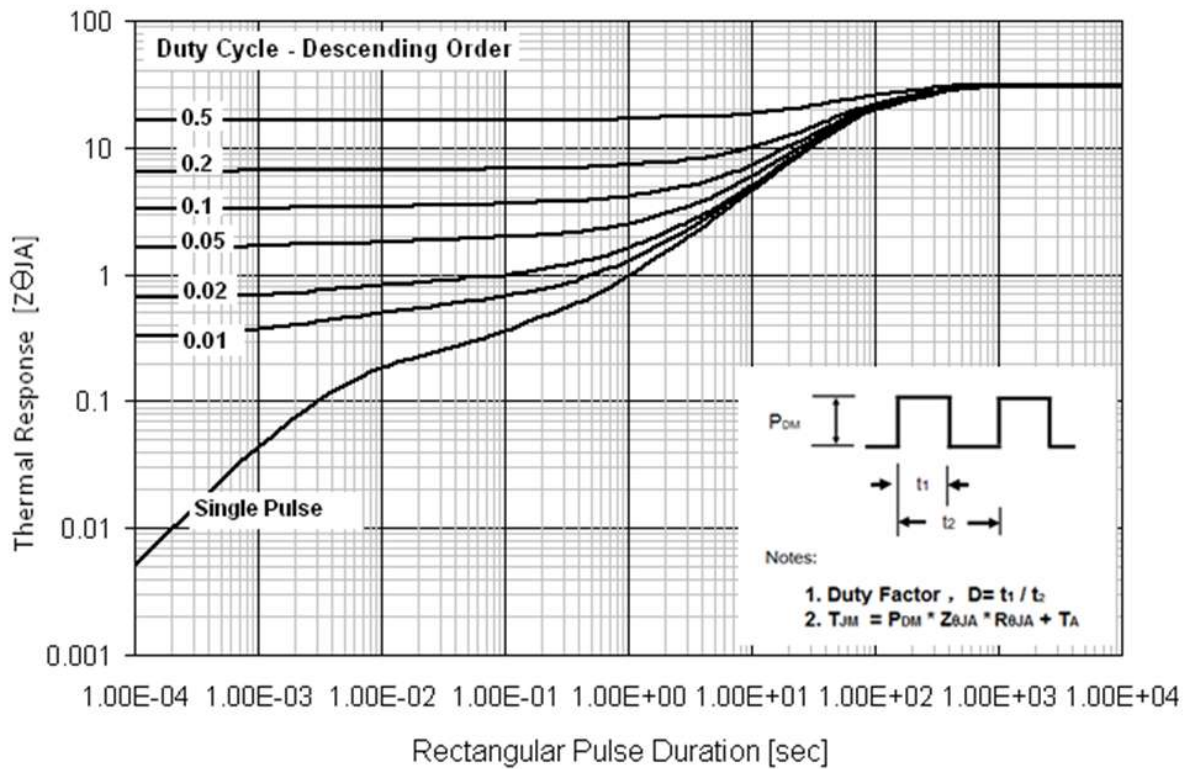
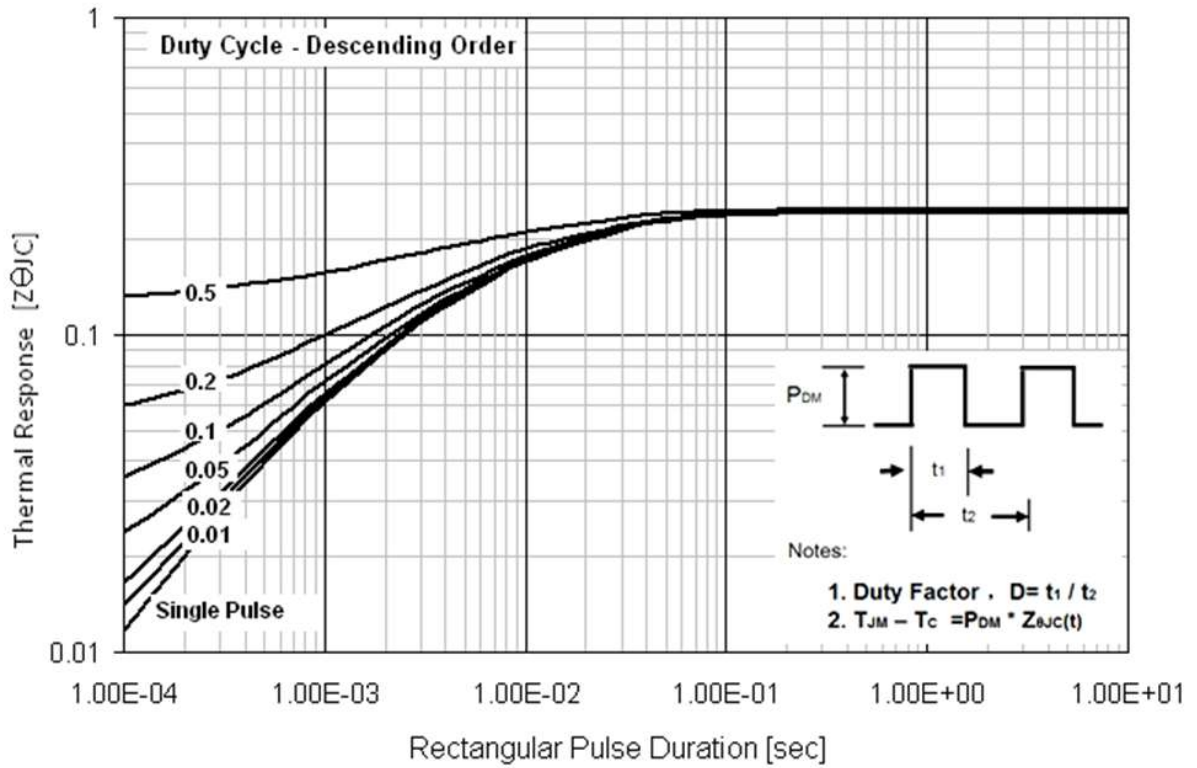


Maximum Drain Current vs. Case Temperature



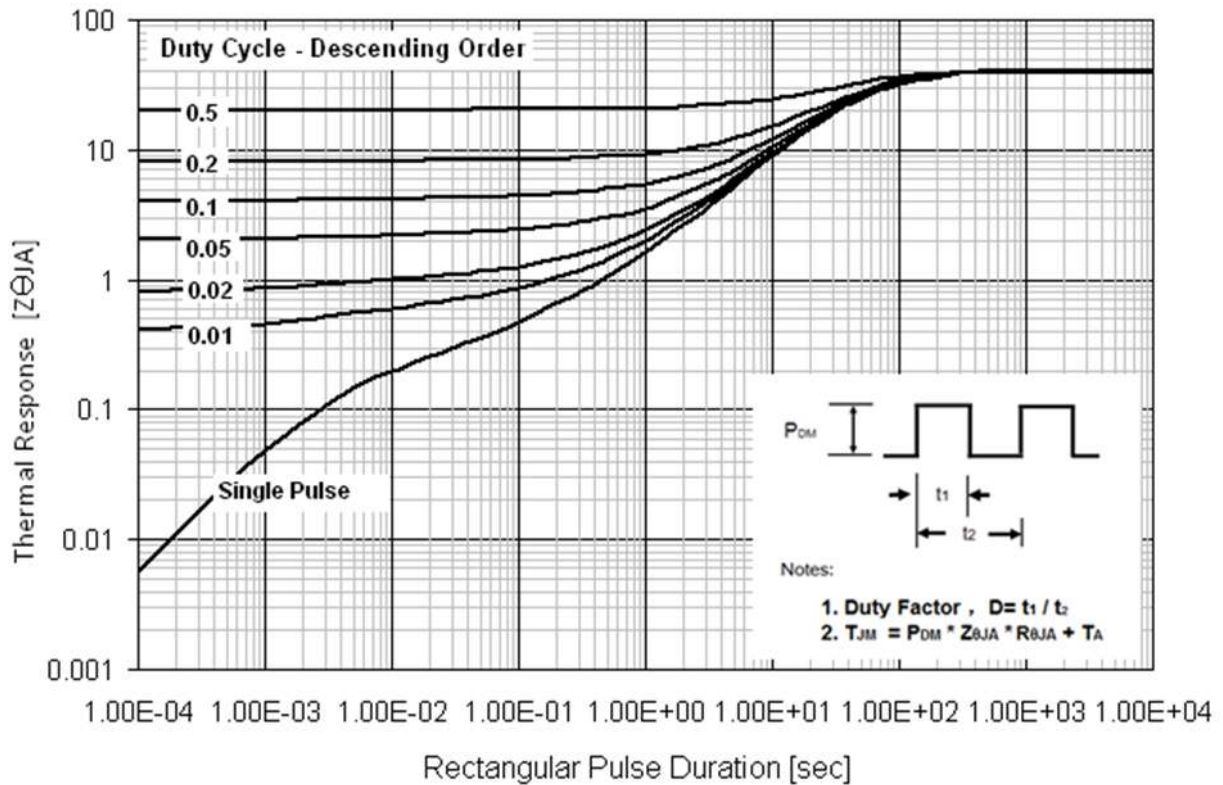
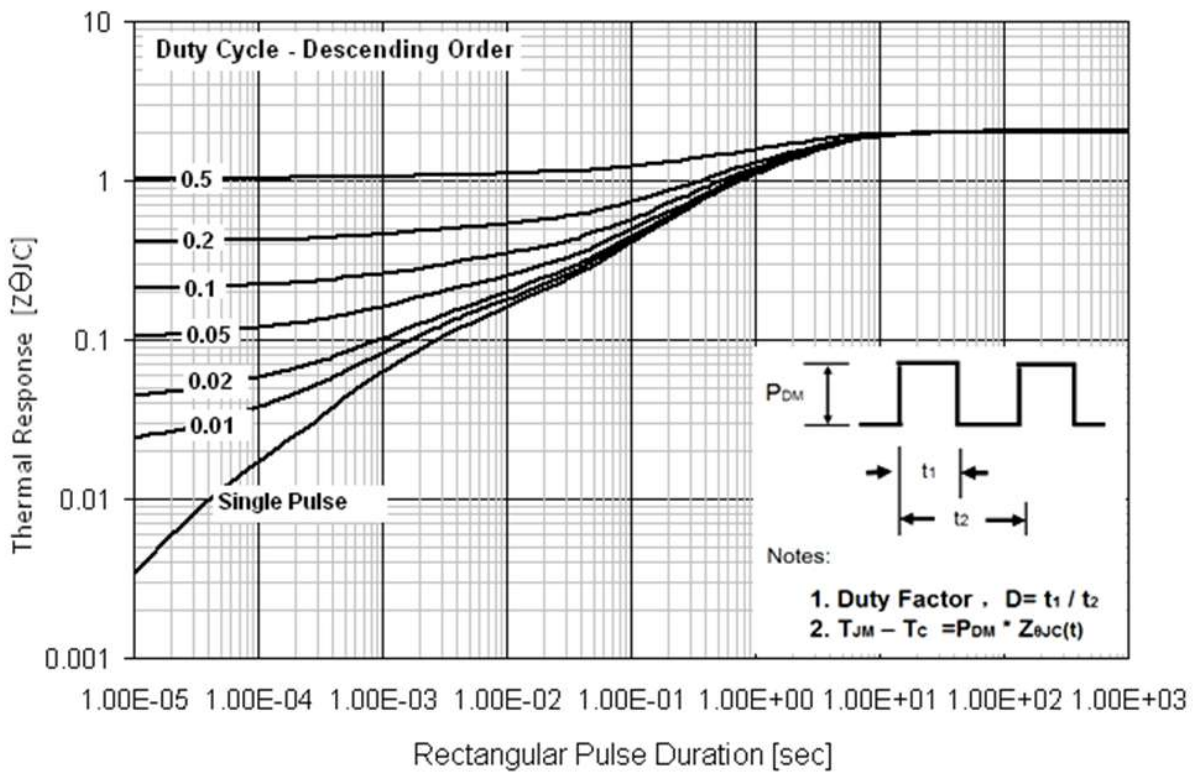


Transient Thermal Response Curve For JCS20N65WH





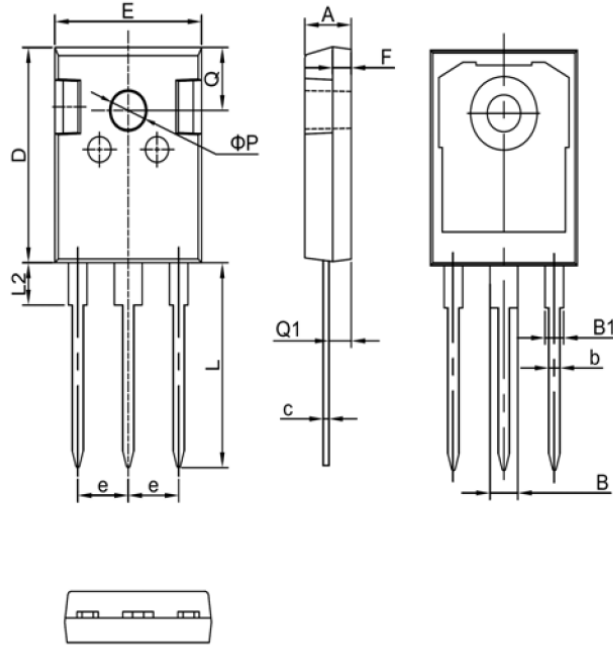
**Transient Thermal Response Curve
For JCS20N65FH**





TO-247

单位 Unit: mm



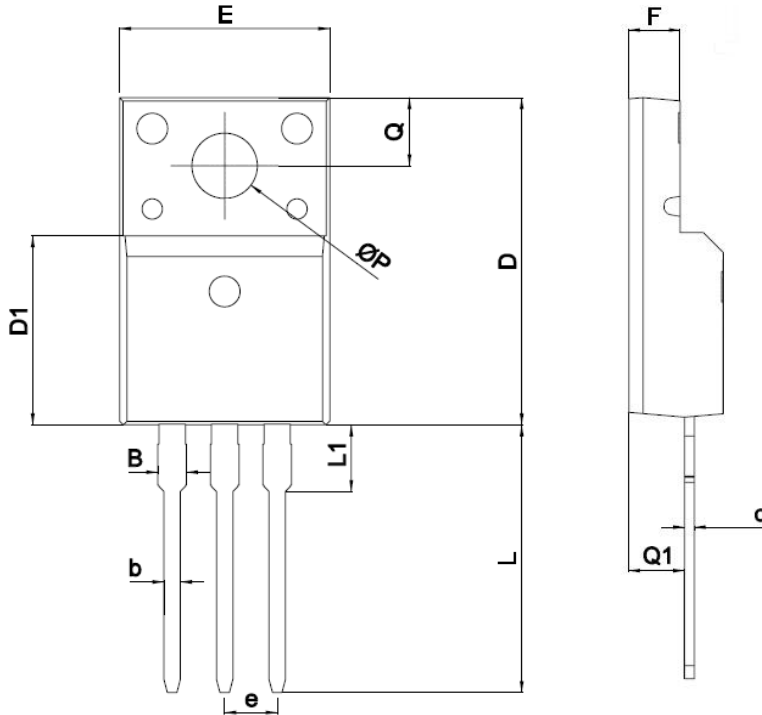
符号 symbol	MIN	MAX
A	4.90	5.10
B	2.95	3.35
B1	1.95	2.35
b	1.15	1.35
c	0.50	0.70
D	20.90	21.10
E	15.70	15.90
e	5.34	5.54
F	1.90	2.10
L	19.40	20.40
L2	4.03	4.23
Q	6.00	6.40
Q1	2.30	2.50
P	3.50	3.70



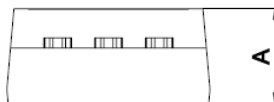


TO-220MF

单位 Unit: mm



SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B		1.47
b	0.7	0.9
c	0.45	0.60
D	15.67	16.07
D1	9.04	9.20
e	2.54TYPE	
E	9.96	10.36
F	2.34	2.74
L	12.58	13.38
L1	3.13	3.33
Q	3.2	3.4
Q1	2.56	2.96
ΦP	3.08	3.28



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联系方式**吉林华微电子股份有限公司**

公司地址：吉林省吉林市深圳街 99 号

邮编：132013

总机：86-432-64678411

传真：86-432-64665812

网址：www.hwdz.com.cn

市场营销部

地址：吉林省吉林市深圳街 99 号

邮编：132013

电话：86-432-64675588

64675688

64678411

传真：86-432-64671533

CONTACT**JILIN SINO-MICROELECTRONICS CO., LTD.**

ADD: No.99 Shenzhen Street, Jilin City, Jilin Province, China.

Post Code: 132013

Tel: 86-432-64678411

Fax: 86-432-64665812

Web Site: www.hwdz.com.cn

MARKET DEPARTMENT

ADD: No.99 Shenzhen Street, Jilin City, Jilin Province, China.

Post Code: 132013

Tel: 86-432-64675588

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Fax: 86-432-64671533



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